## NSN 5962-01-079-7833

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-079-7833
Body Length:
Between 1.100 inches and 1.250 inches
Body Width:
Between 0.580 inches and 0.620 inches
Body Height:
Between 0.140 inches and 0.180 inches
Operating Tempurature Range:
-65.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and monolithic and w/enable and positive outputs and w/storage and w/open collector
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
175.00 nanoseconds propagation delay time, low to high level output and 175.00 nanoseconds propagation delay time, high to low leve
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
51628-530067 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:

**Fiig:** A458a0

Yes - demil/mli